

SB02-15

Shottky Barrier Diode

150V, 200mA Rectifier

Applications

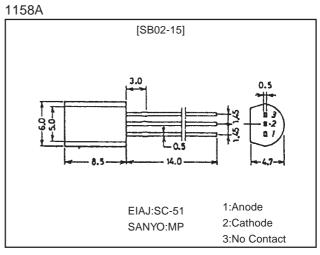
• High frequency rectification (switching regulators, converters, choppers).

Features

- \cdot Low forward voltage (V_F max=0.75V).
- Fast reverse recorvery time (trr max=10ns).
- · Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.

Package Dimensions

unit:mm



Specifications

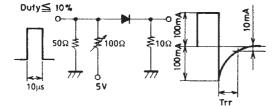
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		150	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		155	V
Average Output Current	IO	50Hz, resistive load, Ta=88°C	200	mA
Surge Forward Current	IFSM	50Hz sine wave, 1cycle	10	A
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		–55 to +125	°C

Electrical Characteristics at Ta = 25°C

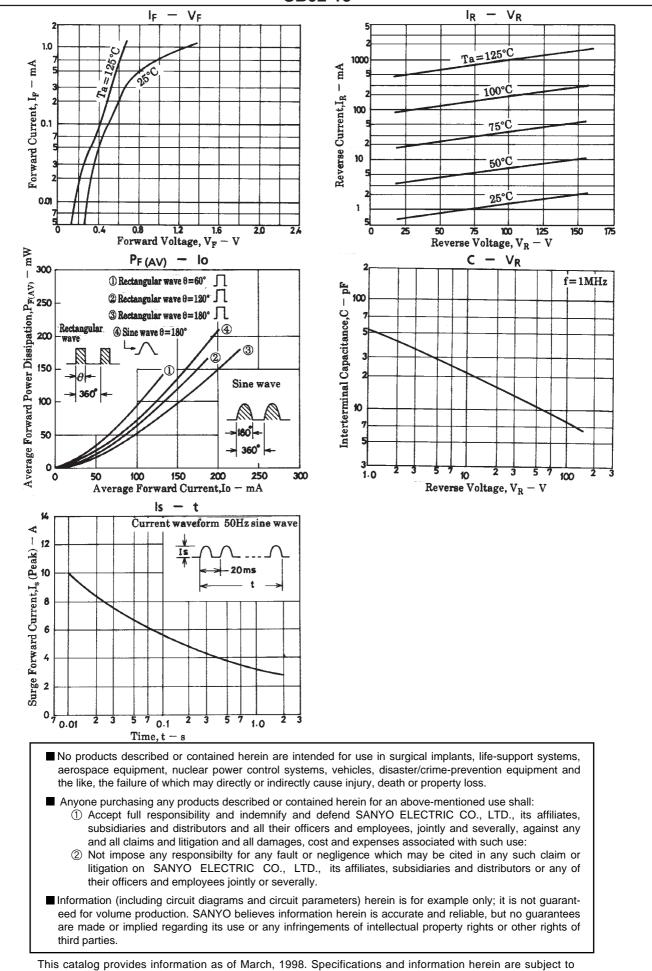
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	VR	I _R =300μA	150			V
Forward Voltage	٧ _F	I _F =200mA			0.75	V
Reverse Current	I _R	V _R =75V			80	μA
Interterminal Capacitance	С	V _R =10V, f=1MHz		22		pF
Reverse Recorvery Time	trr	IF=IR=100mA, See specified Test Circuit			10	ns
Thermal Resistance	Rthj-a			110		°C/W

ttr Test Circuit



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change without notice.